## Appln No. Not Assigned Amdt date June 24, 2003

This listing of claims will replace all prior versions, and listings, of claims in the application:

## Listing of Claims:

Claims 1- 18 (cancelled)

19. (New) A method of coupling a device operating at voiceband frequencies in parallel with a device operating at frequencies above voiceband comprising:

inserting at an input interface between the device operating at voiceband frequencies and the device operating at frequencies above voiceband a series pair of inductors, a first inductor of the series pair having a low inductance and a high self-resonant frequency and a second inductor of the series pair having a high inductance and low self-resonant frequency, the low inductance, the high self-resonant frequency, the high inductance and the low self-resonant frequency being each determined to locate a filtering cutoff point between the voiceband frequencies and the frequencies above voiceband.

- 20. (New) The method of claim 19, wherein the frequencies above voiceband are digital subscriber line frequencies from a 26kHz to 1.104MHz frequency range.
- 21. (New) The method of claim 19, wherein the frequencies above voiceband are home phoneline frequencies from a 4Mhz to 10Mhz frequency range.
- 22. (New) The method of claim 19, wherein the device operating at voiceband frequencies is a facsimile device.

## Appln No. Not Assigned Amdt date June 24, 2003

- 23. (New) The method of claim 19, wherein the input interface is a common RJ-11 phoneline connection.
- 24. (New) The method of claim 19, wherein the low inductance is  $47~\mu H$  and the high inductance is 5~mH.
- 25. (New) An interface circuit between a device operating at voiceband frequencies in parallel with a device operating at frequencies above voiceband comprising:
- a series pair of inductors coupled between an input of the device operating at voiceband frequencies and an input of the device operating at frequencies above voiceband, a first inductor of the series pair having a low inductance and a high self-resonant frequency, and a second inductor of the series pair having a high inductance and low self-resonant frequency, the low inductance, the high self-resonant frequency, the high inductance and the low self-resonant frequency being each determined to locate a filtering cutoff point between the voiceband frequencies and the frequencies above voiceband.
- 26. (New) The interface circuit of claim 25, wherein the frequencies above voiceband are digital subscriber line frequencies from a 26kHz to 1.104MHz frequency range.
- 27. (New) The interface circuit of claim 25, wherein the frequencies above voiceband are home phoneline frequencies from a 4Mhz to 10Mhz frequency range.
- 28. (New) The interface circuit of claim 25, wherein the device operating at voiceband frequencies is a facsimile device.

## Appln No. Not Assigned Amdt date June 24, 2003

- 29. (New) The interface circuit of claim 25, wherein the input of the device operating at voiceband frequencies and the input of the device operating at frequencies above voiceband is a common RJ-11 phoneline connection.
- 30. (New) The interface circuit of claim 25, wherein the low inductance is 47  $\mu H$  and the high inductance is 5 mH.